Randy L. Hoffman

Inventor(s):

PATENT APPLICATION

ATTORNEY DOCKET NO. 200315134-1

Confirmation No.:

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Application No.	:	Examiner:
Filing Date:	Herewith	Group Art Unit:
Title:	SEMICONDUCTOR DEVICE	
Commissioner f PO Box 1450 Alexandria, VA		
Sir:	IN STANKE DISSESSED STATEMENT	
(X) und (Wit mail () und	ation Disclosure Statement is submitted: ler 37 CFR 1.97(b), or hin three months of filing national application; or date of entry of na ing date of first office action on the merits; whichever occurs last) ler 37 CFR 1.97(c) together with either a:	tional application; or before
() (Aft () und ()	Statement under 37 CFR 1.97(e), or a \$180.00 fee under 37 CFR 1.17(p), or set the CFR 1.97 (b) time period, but before final action or notice of allow ler 37 CFR 1.97 (d) together with a: Statement under 37 CFR 1.97(e)(1) or (2), and a \$180.00 fee set forth in 37 CFR 1.17(p). (Filed after final action, a notice of allowance, on or before payment of the set of	
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any required co applicant(s) beli	nt(s) submit herewith Form PTO 1449 - Information Disclepies of patents, publications or other information of which eve(s) may be material to the examination of this application in accordance with 37 CFR 1.56.	applicant(s) are aware, which
and other forei individuals(s) do attached sheet, foreign patent report or action	e explanation of the relevance of foreign language patents ign language information listed on PTO Form 1449, as esignated in 37 CFR 1.56 (c) most knowledgeable about or where a foreign language patent is cited in a searc office in a counterpart foreign application, an English la which indicates the degree of relevance found by the fore closed herewith.	presently understood by the the content is given on the ch report or other action by a singuage version of the search
It is requested t	hat the information disclosed herein be made of record in t	his application.

Typed Name: Sarah L. Reinhard

for

Commissioner

Rev 10/03 (IDSXML)

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Date of Deposit 03/12/2004

I hereby certify that this is being deposited with the United States Postal Service "Express Mail Post Office to Addressee" service under 37 CFR 1.10 on the date indicated above and is addressed to:

Patents,

Alexandria,

Edward J. Brooks III

Respectfully submitted,

Randy L. Hoffmein

Attorney/Agent for Applicant(s)

Reg. No. 40,925

Date: 03/12/2004

Telephone No.: (612) 659-9340

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